

Switchmode Full Plastic Single Ultra-fast Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- *High Surge Capacity
- *Low Power Loss, High efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- * High-Switching Speed 50 Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- *Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

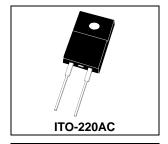
Characteristic	Symbol	URAF1560	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectifier Forward Current	I _{F(AV)}	15	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	15	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	225	А
Operating and Storage Junction Temperature Range	T_J , T_stg	-65 to +150	$^{\circ}\!\mathbb{C}$

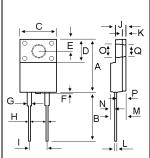
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 15 \text{ Amp } T_C = 25^{\circ}\text{C}$) ($I_F = 15 \text{ Amp } T_C = 125^{\circ}\text{C}$)	V _F		1.20 1.00	1.60	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R		0.01 5	10 	uA
Typical Thermal Resistance junction to case	$R_{ heta jc}$		2.0		°C/w
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A)	T _{rr}		35	50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР		100		₽F

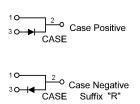
ULTRA FAST RECTIFIERS

15 AMPERES 600 VOLTS

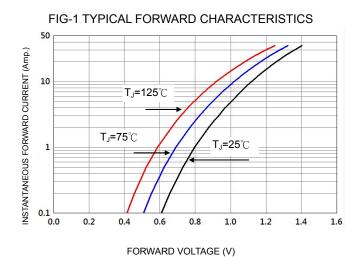


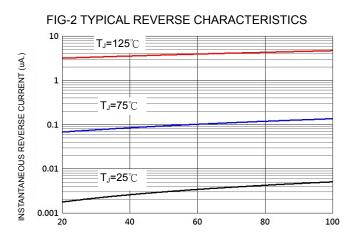


DIM	MILLIM	ETERS	
DIIVI	MIN	MAX	
Α	14.80	16.10	
В	12.65	13.80	
С	9.85	10.36	
D	4.60	6.80	
E	2.50	3.50	
F		2.00	
G	1.00	1.45	
Н	0.30	0.90	
- 1	4.80	5.40	
J	2.34	3.30	
K	0.55	1.30	
L	0.36	0.80	
M	4.20	4.90	
N	1.10	1.80	
0	2.90	3.50	
Р	2.50	3.15	
Q	2.90	3.50	

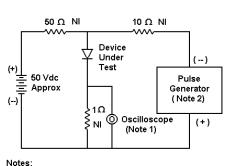


MAMOSPEC



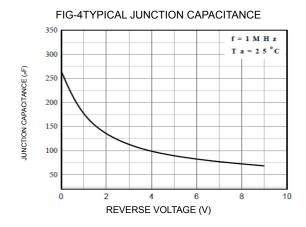


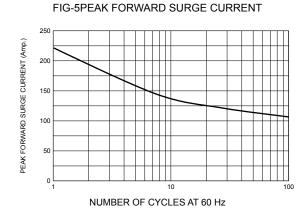
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

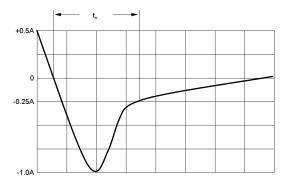


1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE 15 12 12 12 0 0 25 50 75 100 125 150 LEAD TEMPERATURE (°C')







Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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